MASW-008853

GaAs SPDT 2.7 V High Power Switch
DC - 5.0 GHz

Features
- Low Voltage Operation: 2.7 V
- High Power: +38dBm (typ) P0.1dB
- High IP3: +56 dBm
- Low Insertion Loss: 0.25 dB @ 1 GHz
- High Isolation: 25 dB @ 1 GHz
- Lead-Free SC70 Package
- 100% Matte Tin Plating over Copper
- Halogen-Free “Green” Mold Compound
- RoHS* Compliant and 260°C Reflow Compatible

Description
M/A-COM's MASW-008853 is a GaAs PHEMT MMIC single pole double throw (SPDT) high power switch in a low cost SC70 six lead package. The MASW-008853 is ideally suited for applications where high power, low control voltage, low insertion loss, high isolation, small size, and low cost are required.

Typical applications are for CDMA handset systems that connect separate transceiver and/or GPS functions to a common antenna, as well as other related handset and general purpose applications. The MASW-008853 can be used in all systems operating up to 5.0 GHz requiring high power at low control voltage.

The MASW-008853 is fabricated using a 0.5 micron gate length GaAs pHEMT process. The process features full passivation for performance and reliability.

Ordering Information 1,2

<table>
<thead>
<tr>
<th>Part Number</th>
<th>Package</th>
</tr>
</thead>
<tbody>
<tr>
<td>MASW-008853-000000</td>
<td>Bulk Packaging</td>
</tr>
<tr>
<td>MASW-008853-TR3000</td>
<td>3000 piece reel</td>
</tr>
<tr>
<td>MASW-008853-001SMB</td>
<td>Sample Test Board</td>
</tr>
</tbody>
</table>

1. Reference Application Note M513 for reel size information.
2. All sample boards include 5 loose parts.

Functional Block Diagram

Pin Configuration

<table>
<thead>
<tr>
<th>Pin No.</th>
<th>Pin Name</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>RF1</td>
<td>RF Port 1</td>
</tr>
<tr>
<td>2</td>
<td>GND</td>
<td>RF Ground</td>
</tr>
<tr>
<td>3</td>
<td>RF2</td>
<td>RF Port 2</td>
</tr>
<tr>
<td>4</td>
<td>V2</td>
<td>Vcontrol 2</td>
</tr>
<tr>
<td>5</td>
<td>RFC</td>
<td>RF Common</td>
</tr>
<tr>
<td>6</td>
<td>V1</td>
<td>Vcontrol 1</td>
</tr>
</tbody>
</table>

Absolute Maximum Ratings 3,4

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Absolute Maximum</th>
</tr>
</thead>
<tbody>
<tr>
<td>Input Power (0.5 - 3 GHz, 3 V Control)</td>
<td>+38 dBm</td>
</tr>
<tr>
<td>Operating Voltage</td>
<td>+8.5 volts</td>
</tr>
<tr>
<td>Operating Temperature</td>
<td>-40°C to +85°C</td>
</tr>
<tr>
<td>Storage Temperature</td>
<td>-65°C to +150°C</td>
</tr>
</tbody>
</table>

3. Exceeding any one or combination of these limits may cause permanent damage to this device.
4. M/A-COM does not recommend sustained operation near these survivability limits.

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Electrical Specifications:  \( T_A = 25^\circ C, V_C = 0 \text{ V}/2.7 \text{ V}, Z_0 = 50 \Omega \)

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Units</th>
<th>Min.</th>
<th>Typ.</th>
<th>Max.</th>
</tr>
</thead>
<tbody>
<tr>
<td>Insertion Loss(^6)</td>
<td>1 GHz</td>
<td>dB</td>
<td>—</td>
<td>0.30</td>
<td>0.65</td>
</tr>
<tr>
<td></td>
<td>2 GHz</td>
<td>dB</td>
<td>—</td>
<td>0.36</td>
<td>—</td>
</tr>
<tr>
<td></td>
<td>3 GHz</td>
<td>dB</td>
<td>—</td>
<td>0.45</td>
<td>—</td>
</tr>
<tr>
<td></td>
<td>4 GHz</td>
<td>dB</td>
<td>—</td>
<td>0.70</td>
<td>—</td>
</tr>
<tr>
<td></td>
<td>5 GHz</td>
<td>dB</td>
<td>—</td>
<td>1.10</td>
<td>—</td>
</tr>
<tr>
<td>Isolation</td>
<td>1 GHz</td>
<td>dB</td>
<td>23</td>
<td>25</td>
<td>—</td>
</tr>
<tr>
<td></td>
<td>2 GHz</td>
<td>dB</td>
<td>—</td>
<td>19</td>
<td>—</td>
</tr>
<tr>
<td></td>
<td>3 GHz</td>
<td>dB</td>
<td>—</td>
<td>15</td>
<td>—</td>
</tr>
<tr>
<td></td>
<td>4 GHz</td>
<td>dB</td>
<td>—</td>
<td>13</td>
<td>—</td>
</tr>
<tr>
<td></td>
<td>5 GHz</td>
<td>dB</td>
<td>—</td>
<td>11</td>
<td>—</td>
</tr>
<tr>
<td>Return Loss</td>
<td>DC – 3 GHz</td>
<td>dB</td>
<td>—</td>
<td>20</td>
<td>—</td>
</tr>
<tr>
<td>IP3</td>
<td>825 MHz</td>
<td>dBm</td>
<td>—</td>
<td>56</td>
<td>—</td>
</tr>
<tr>
<td></td>
<td>Two Tone, +24 dBm Total Pin, 5 MHz Spacing</td>
<td>dBm</td>
<td>—</td>
<td>—</td>
<td>—</td>
</tr>
<tr>
<td>Cross Modulation</td>
<td>Two-tone signal input: ( Tx1 = +22 \text{ dBm} @ 820 \text{ MHz}, ) ( R_x ) interfere = -23 dBm @ 869 MHz</td>
<td>dBm</td>
<td>—</td>
<td>-99</td>
<td>—</td>
</tr>
<tr>
<td></td>
<td>Two-tone signal input: ( Tx1 = +18 \text{ dBm} @ 1880 \text{ MHz}, ) ( Tx2 = +18 \text{ dBm} @ 1881 \text{ MHz}, ) ( R_x ) interfere = -23 dBm @ 1960 MHz</td>
<td>dBm</td>
<td>—</td>
<td>-94</td>
<td>—</td>
</tr>
<tr>
<td>P0.1dB</td>
<td>1 GHz</td>
<td>dBm</td>
<td>—</td>
<td>38</td>
<td>—</td>
</tr>
<tr>
<td>Trise, Tfall</td>
<td>10% to 90% RF, 90% to 10% RF</td>
<td>nS</td>
<td>—</td>
<td>70</td>
<td>—</td>
</tr>
<tr>
<td>Ton, Toff</td>
<td>50% control to 90% RF, 50% control to 10% RF</td>
<td>nS</td>
<td>—</td>
<td>100</td>
<td>—</td>
</tr>
<tr>
<td>Transients</td>
<td>In Band</td>
<td>mV</td>
<td>—</td>
<td>25</td>
<td>—</td>
</tr>
<tr>
<td>Control Current</td>
<td>( V_C = 2.7 \text{ V} )</td>
<td>( \mu A )</td>
<td>—</td>
<td>5</td>
<td>20</td>
</tr>
</tbody>
</table>

5. For positive voltage control, external DC blocking capacitors are required on all RF ports.
6. Insertion loss can be optimized by varying the DC blocking capacitor value, e.g. 1000 pF for 100 MHz - 1 GHz, 39 pF for 0.5 GHz - 3 GHz.

Truth Table \(^7,8,9\)

<table>
<thead>
<tr>
<th>V1</th>
<th>V2</th>
<th>ANT–RF1</th>
<th>ANT - RF2</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>0</td>
<td>On</td>
<td>Off</td>
</tr>
<tr>
<td>0</td>
<td>1</td>
<td>Off</td>
<td>On</td>
</tr>
</tbody>
</table>

7. For positive voltage control, external DC blocking capacitors are required on all RF ports.
8. Differential voltage, \( V(\text{state 1}) - V(\text{state 0}) \), must be +2.7 V minimum, but must not exceed 8.5 V.
9. \( 0 = -5 \text{ V to } +2.3 \text{ V}, 1 = -2.3 \text{ V to } +5 \text{ V} \).

Qualification

Handling Procedures
Please observe the following precautions to avoid damage:

Static Sensitivity
Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.
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Typical Performance Curves, 1000 pF

**Insertion Loss**

![Insertion Loss Graph](image1)

**Isolation**

![Isolation Graph](image2)

**RFC Return Loss**

![RFC Return Loss Graph](image3)

**RF1/RF2 Return Loss**

![RF1/RF2 Return Loss Graph](image4)

**Lead-Free SC70 Plastic Package†**

![Lead-Free SC70 Plastic Package](image5)

† Reference Application Note M538 for lead-free solder reflow recommendations.

Meets JEDEC moisture sensitivity level 1 requirements.